

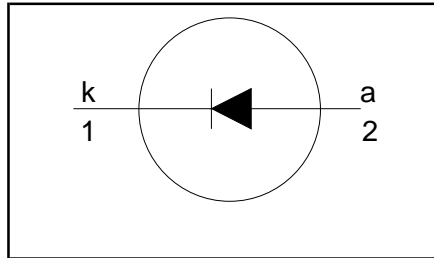
Rectifier diodes ultrafast, rugged

BYW29E series

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$V_R = 100V/ 150 V/ 200 V$
$V_F \leq 0.895 V$
$I_{F(AV)} = 8 A$
$I_{RRM} \leq 0.2 A$
$t_{tr} \leq 25 ns$

GENERAL DESCRIPTION

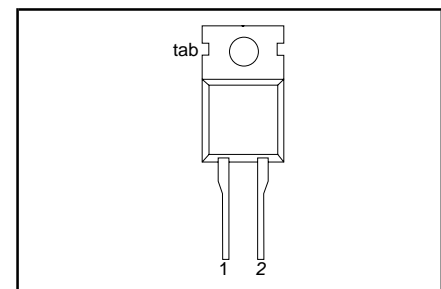
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYW29E series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
				-100	-150	-200	
V_{RRM}	Peak repetitive reverse voltage	BYW29E	-	100	150	200	V
V_{RWM}	Working peak reverse voltage		-	100	150	200	V
V_R	Continuous reverse voltage		-	100	150	200	V
$I_{F(AV)}$	Average rectified forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 128 \text{ }^\circ\text{C}$	-	8			A
I_{FRM}	Repetitive peak forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 128 \text{ }^\circ\text{C}$	-	16			A
I_{FSM}	Non-repetitive peak forward current	$t = 10 \text{ ms}$	-	80			A
		$t = 8.3 \text{ ms}$	-	88			A
I_{RRM}	Peak repetitive reverse surge current	sinusoidal; with reapplied $V_{RRM(max)}$ $t_p = 2 \text{ } \mu\text{s}$; $\delta = 0.001$	-	0.2			A
I_{RSM}	Peak non-repetitive reverse surge current	$t_p = 100 \text{ } \mu\text{s}$	-	0.2			A
T_j	Operating junction temperature		-	150			$^\circ\text{C}$
T_{stg}	Storage temperature		- 40	150			$^\circ\text{C}$

ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_C	Electrostatic discharge capacitor voltage	Human body model; $C = 250 \text{ pF}$; $R = 1.5 \text{ k}\Omega$	-	8	kV

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base		-	-	2.7	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	in free air	-	60	-	K/W

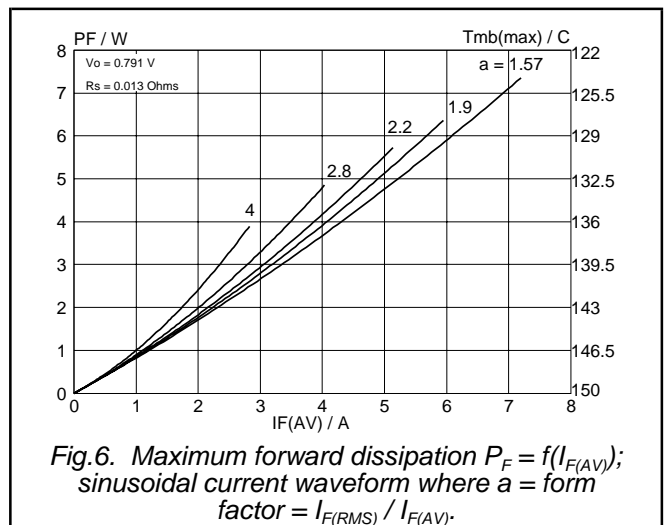
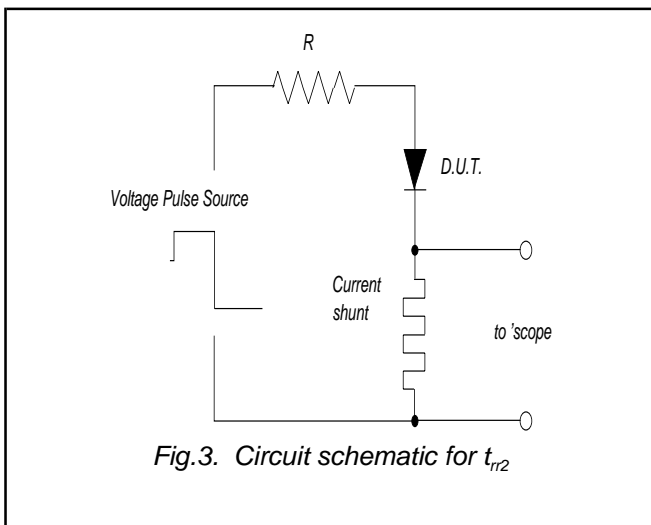
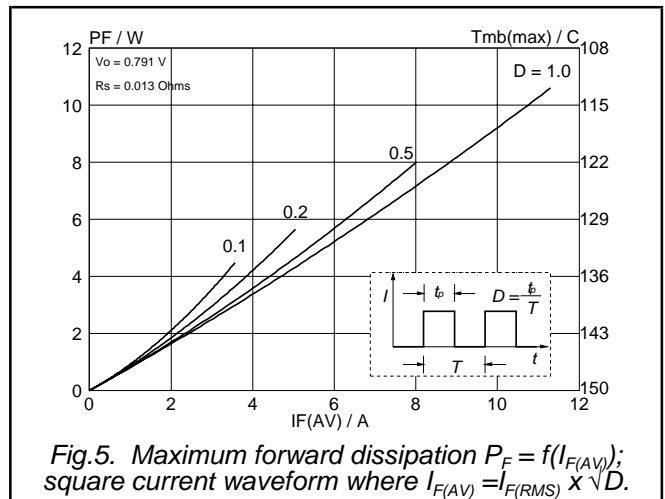
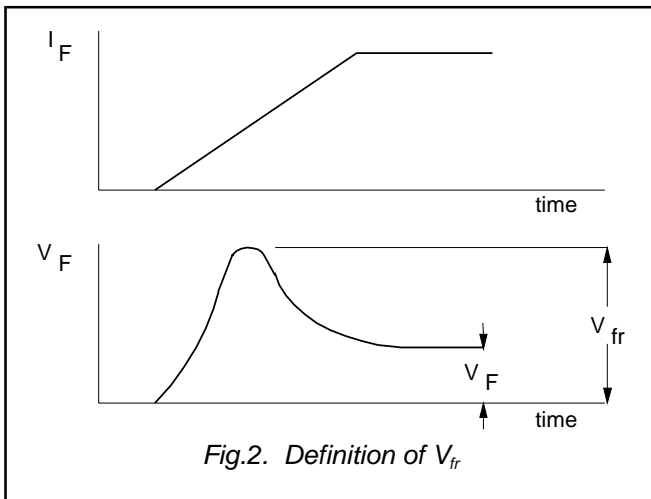
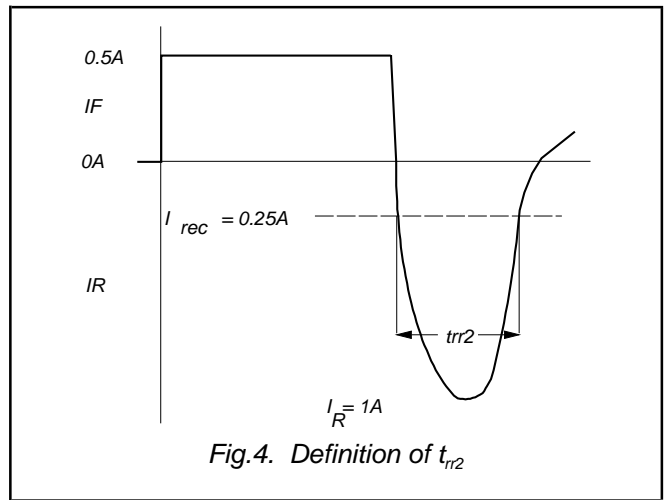
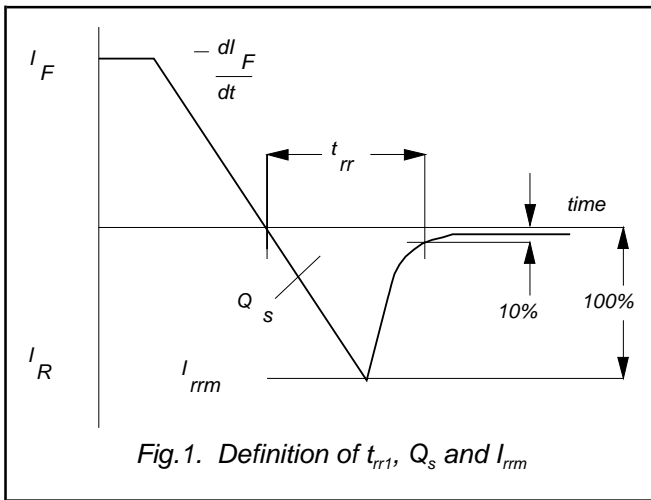
ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 8\text{ A}; T_j = 150\text{ °C}$	-	0.8	0.895	V
		$I_F = 8\text{ A}$	-	0.92	1.05	V
		$I_F = 20\text{ A}$	-	1.1	1.3	V
I_R	Reverse current	$V_R = V_{RWM}$	-	2	10	μA
		$V_R = V_{RWM}; T_j = 100\text{ °C}$	-	0.2	0.6	mA
Q_{rr}	Reverse recovered charge	$I_F = 2\text{ A}; V_R \geq 30\text{ V}; -di_F/dt = 20\text{ A}/\mu\text{s}$	-	4	11	nC
t_{rr1}	Reverse recovery time	$I_F = 1\text{ A}; V_R \geq 30\text{ V}; -di_F/dt = 100\text{ A}/\mu\text{s}$	-	20	25	ns
t_{rr2}	Reverse recovery time	$I_F = 0.5\text{ A to } I_R = 1\text{ A}; I_{rec} = 0.25\text{ A}$	-	15	20	ns
V_{fr}	Forward recovery voltage	$I_F = 1\text{ A}; di_F/dt = 10\text{ A}/\mu\text{s}$	-	1	-	V

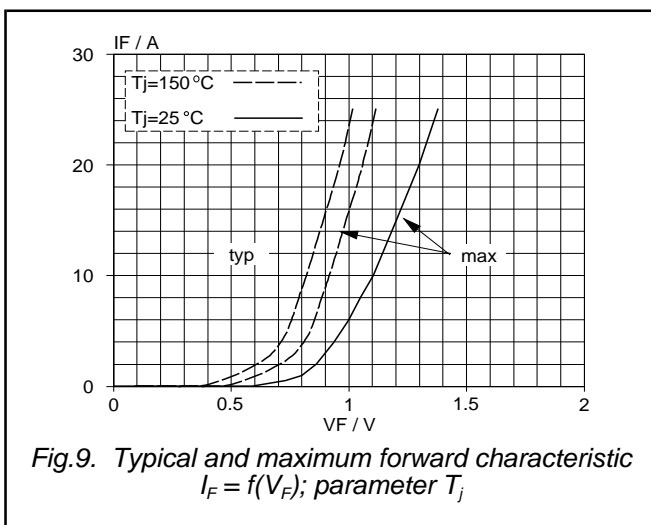
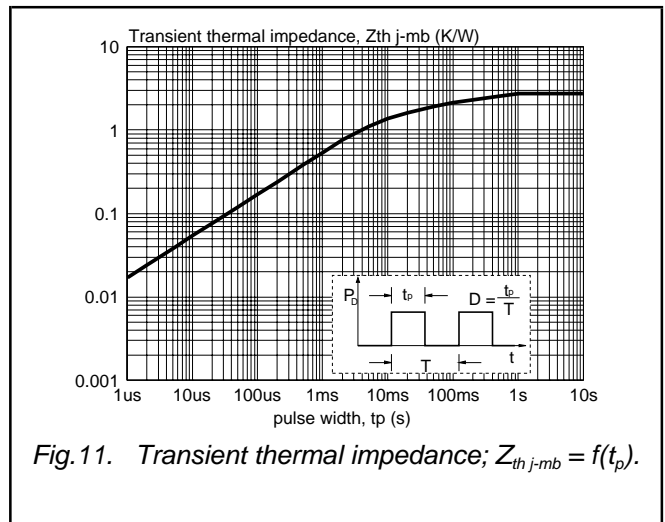
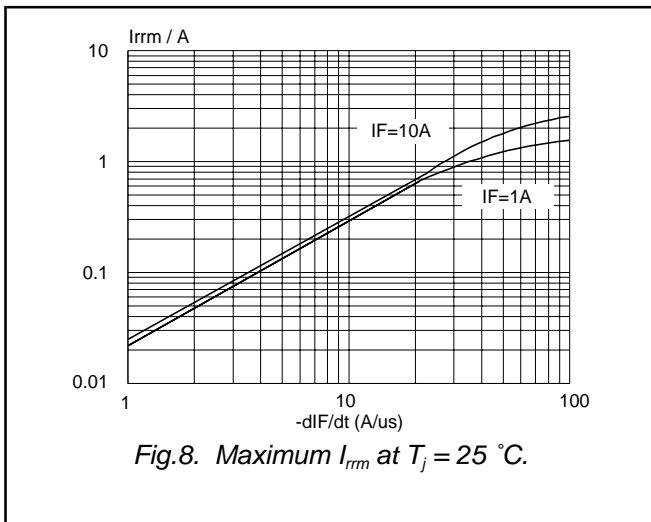
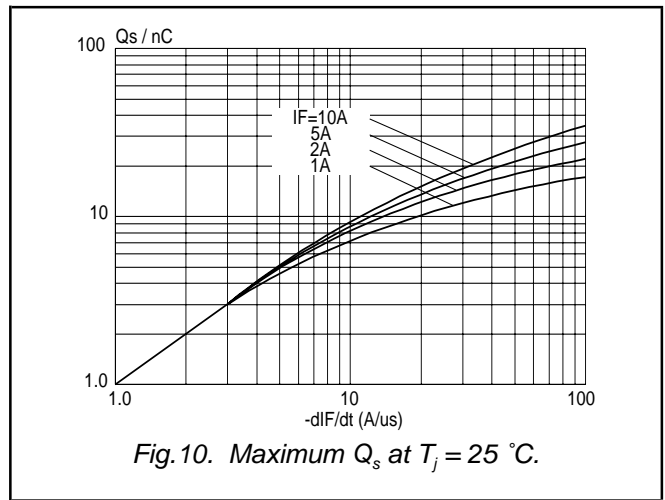
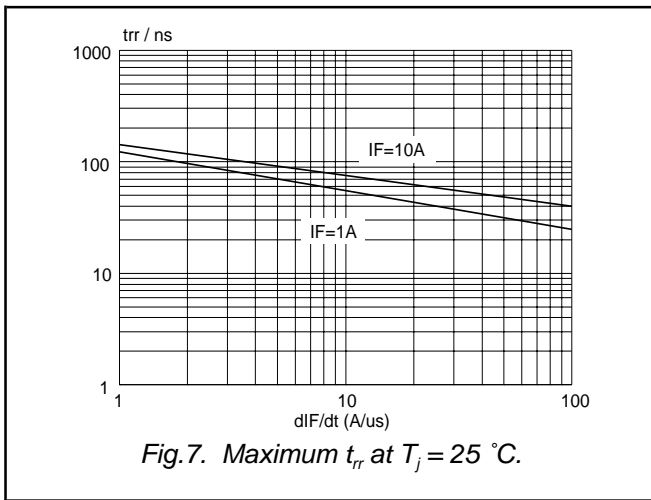
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MECHANICAL DATA

Dimensions in mm Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220

SOD59

Net Mass: 2 g

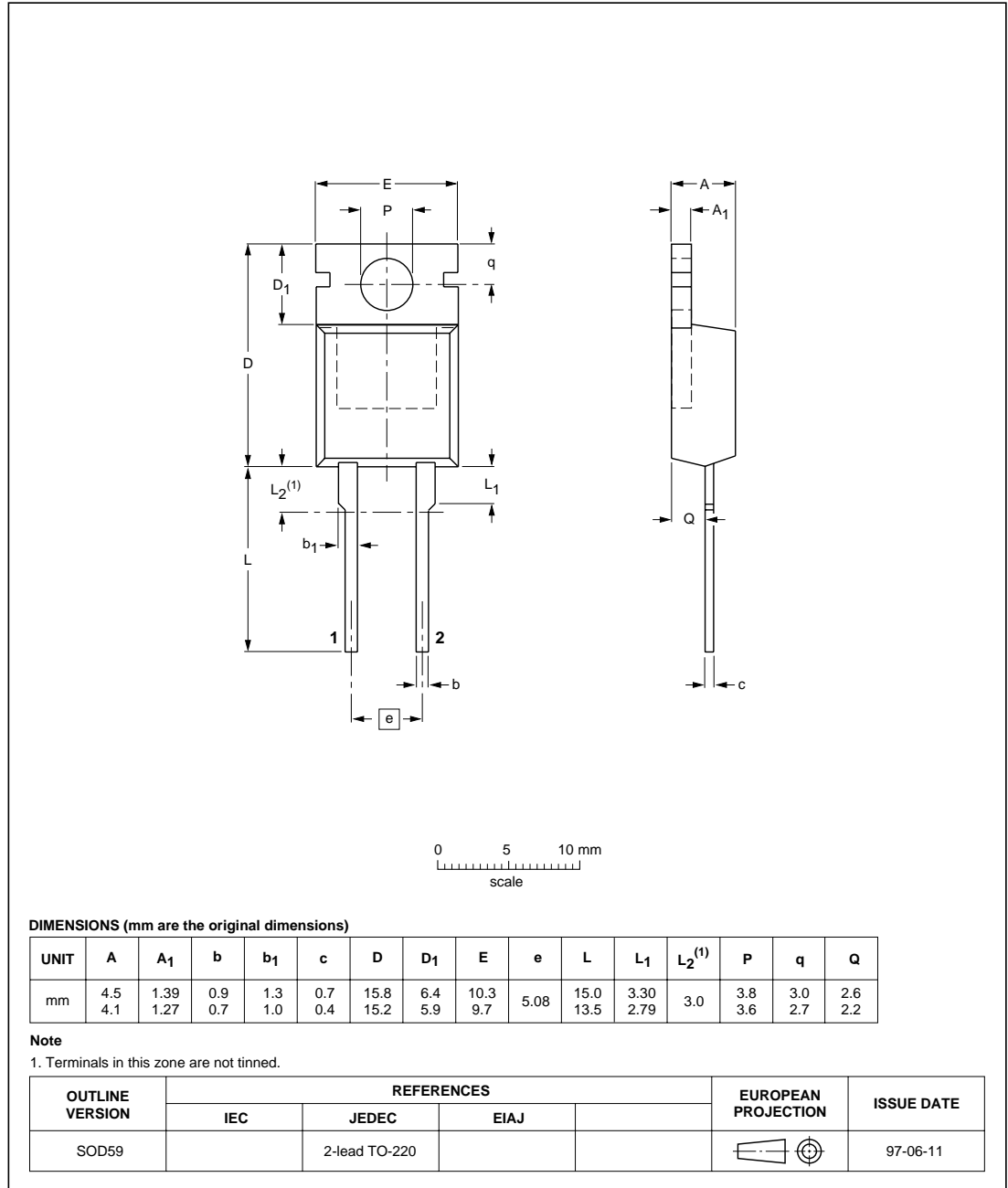


Fig. 12. TO220AC; pin 1 connected to mounting base.

Notes

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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